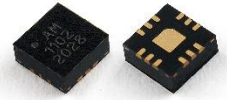


AM1102 – Amplifier

DC to 22 GHz Gain Block

Description

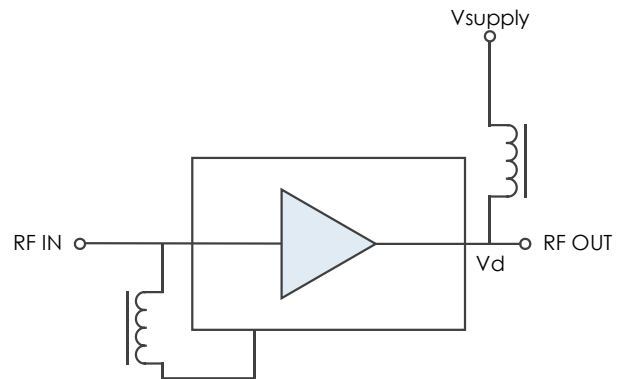
AM1102 is a wideband, cascadable amplifier servicing the DC to 22 GHz frequency range. The device exhibits moderate gain and excellent noise figure over a wide frequency range which makes the AM1102 a useful component for many broadband applications. Packaged in a 3mm QFN with internal 50Ω matching, and drawing less than 160mW of power, the AM1102 is suited for low SWaP applications.



Features

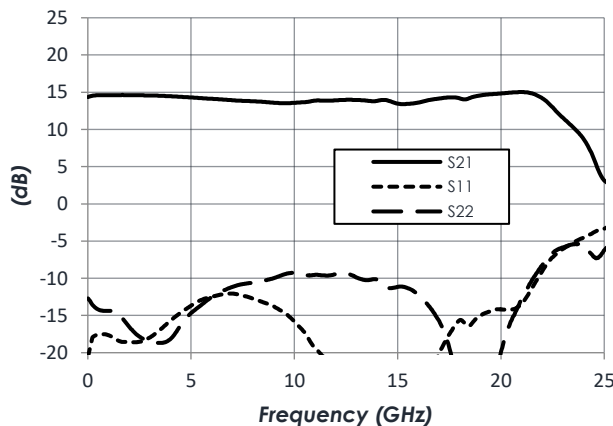
- 14 dB Gain
- 2.3 dB Noise Figure
- +26 dBm OIP3
- +15 dBm P1dB
- +3.3V Operation
- 158 mW Power Consumption
- 3mm QFN
- -40C to +85C Operation

Functional Diagram



Characteristic Performance

Gain and Return Loss at +25C



Noise Figure at +25C

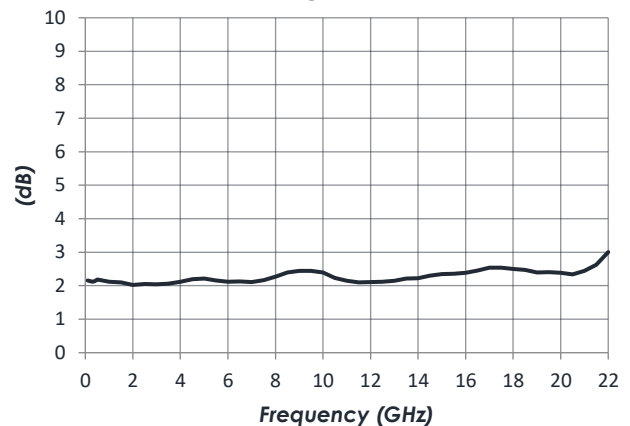


Table of Contents

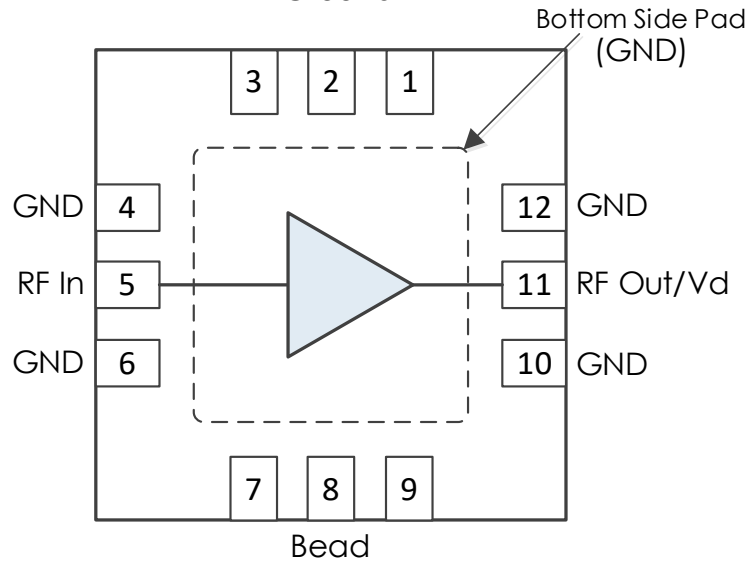
Description	1	Thermal Information	4
Features	1	DC Electrical Characteristics	5
Functional Diagram	1	RF Performance	5
Characteristic Performance	1	Typical Performance	6
Revision History	2	Typical Device Characteristics.....	7
Pin Layout and Definitions	3	Typical Application	8
Specifications	4	Evaluation PC Board	9
Absolute Maximum Ratings.....	4	Related Parts	9
Handling Information.....	4	Component Compliance Information	10
Recommended Operating Conditions....	4		

Revision History

Date	Revision Number	Notes
June 12, 2020	1	Initial Release
February 8, 2021	2	Added Picture and Current Distribution Graph
July 12, 2021	3	Changed Location of Pin 1 Indicator and Added Thermal Resistance
December 6, 2023	3.1	Added notes on bias tee

Pin Layout and Definitions

Note: All Un-Labeled Pins are NC or Ground



Pin Number	Pin Name	Pin Function
1-3	NC	No Connect
4	GND	Ground – Common
5	RF In	RF Input – 50 Ohms – DC Coupled. External DC blocking capacitor required
6	GND	Ground – Common
7	NC	No Connect
8	Bead	Connect to RF In through external ferrite bead or large inductor
9	NC	No Connect
10	GND	Ground – Common
11	RF Out/Vd	RF Output and DC Power Input – 50 Ohms – DC Coupled. External DC blocking capacitor required
12	GND	Ground - Common

AM1102 – Amplifier

DC to 22 GHz Gain Block



Specifications

Absolute Maximum Ratings

	Minimum	Maximum
Supply Voltage	-0.3 V	+3.5 V
RF Input Power		+20 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-55 C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 3	



Atlanta Micro products are electrostatic sensitive.
Follow safe handling practices to avoid damage

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage	+3.0 V	+3.3 V	+3.3 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+125 C

Thermal Information

	Thermal Resistance (°C / W)
Junction to Case Thermal Resistance (θ_{JC})	175

AM1102 – Amplifier

DC to 22 GHz Gain Block

DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
DC Supply Voltage			+3.3 V	
DC Supply Current		40 mA	46 mA	55 mA
Power Dissipated			158 mW	

RF Performance

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
Frequency Range		DC		22 GHz
Gain	f = 0.1 GHz		14.5 dB	
	f = 10 GHz		14 dB	
	f = 21 GHz		15 dB	
Return Loss	f = 0.1 GHz		-14 dB	
	f = 10 GHz		-10 dB	
	f = 21 GHz		-15 dB	
Output IP3	f = 10 GHz		+26 dBm	
Output P1dB	f = 10 GHz		+15 dBm	
Noise Figure	f = 10 GHz		2.3 dB	

Notes:

1. OIP3 measured with 10MHz tone spacing
2. Data measured directly at input and output of device exclusive of external bias tee loss.

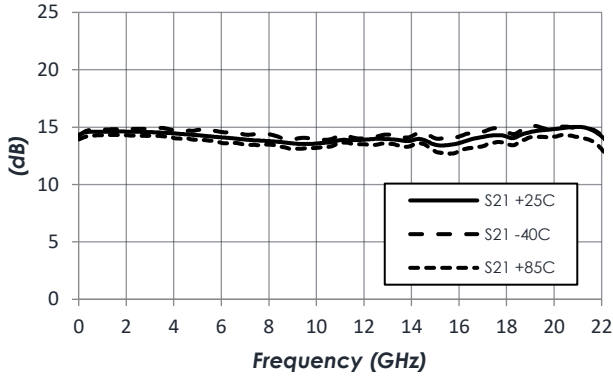
AM1102 – Amplifier

DC to 22 GHz Gain Block

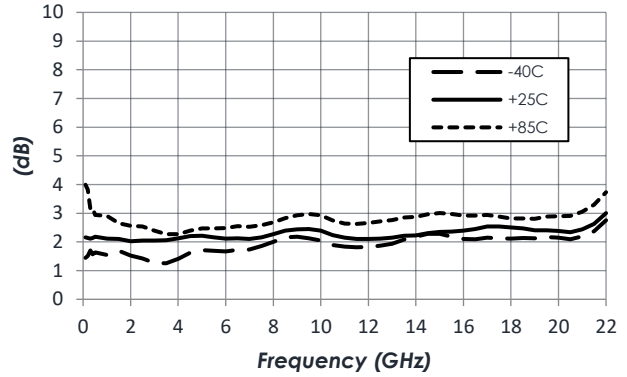
Typical Performance

(VDD = +3.3V, T = 25°C unless otherwise specified)

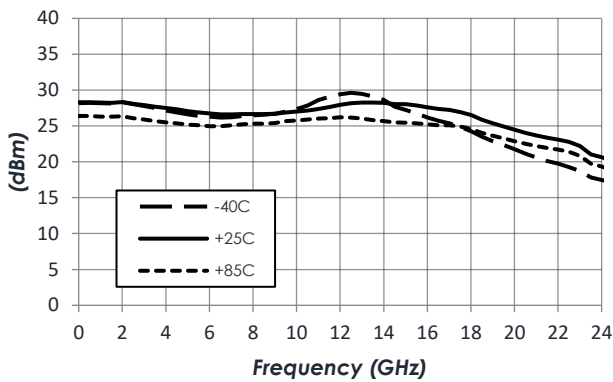
Gain vs Temperature



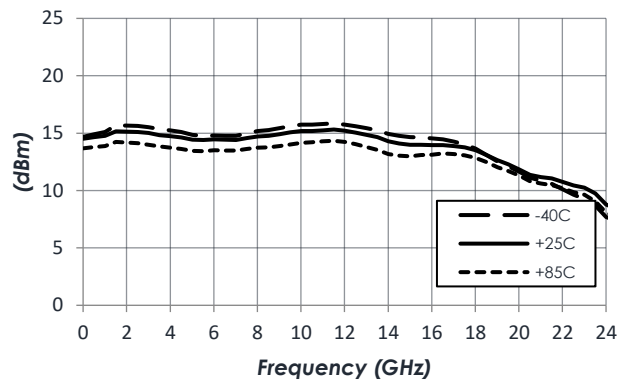
Noise Figure vs Temperature



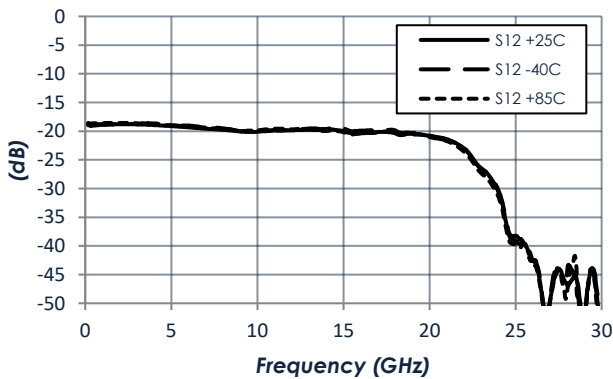
Output IP3 vs Temperature



P1dB vs Temperature



Reverse Isolation vs Temperature



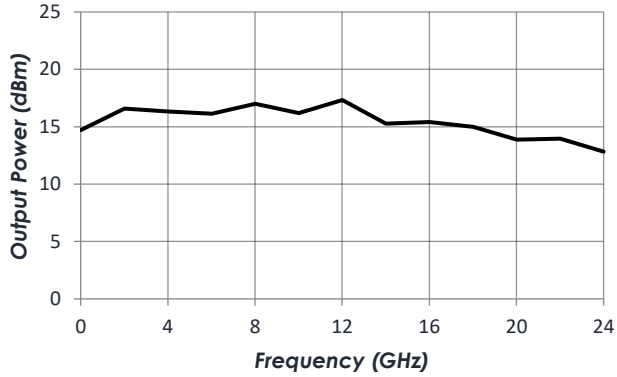
AM1102 – Amplifier

DC to 22 GHz Gain Block

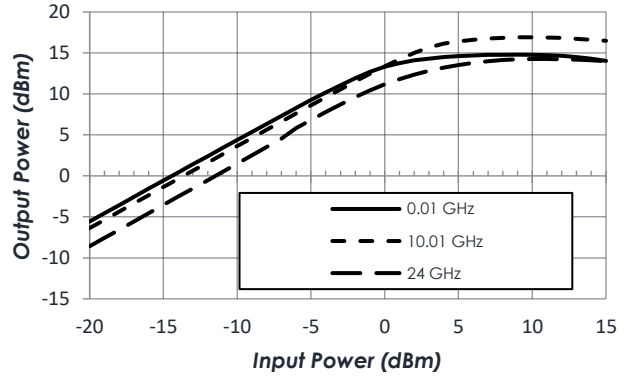
Typical Performance (continued)

(VDD = +3.3V, T = 25°C unless otherwise specified)

P_{Sat} at +25C



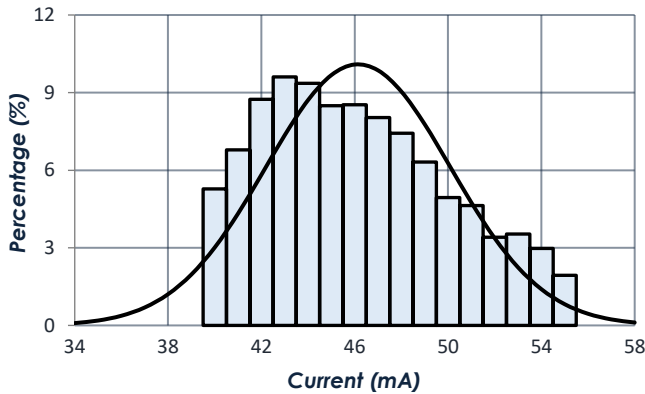
Pin vs. Pout at +25C



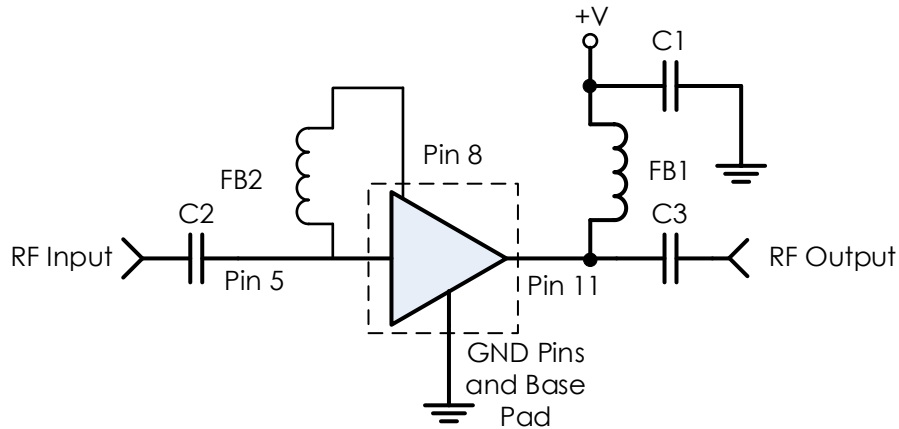
Typical Device Characteristics

(VDD = +3.3V, T = 25°C unless otherwise specified)

Current Distribution



Typical Application



Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1	0.1 μ F	GRM155R71C104KA88	Murata
C2, C3	0.1 μ F	0201BB104KW160	Passives Plus
FB1, FB2	-	MMZ1005A222E	TDK

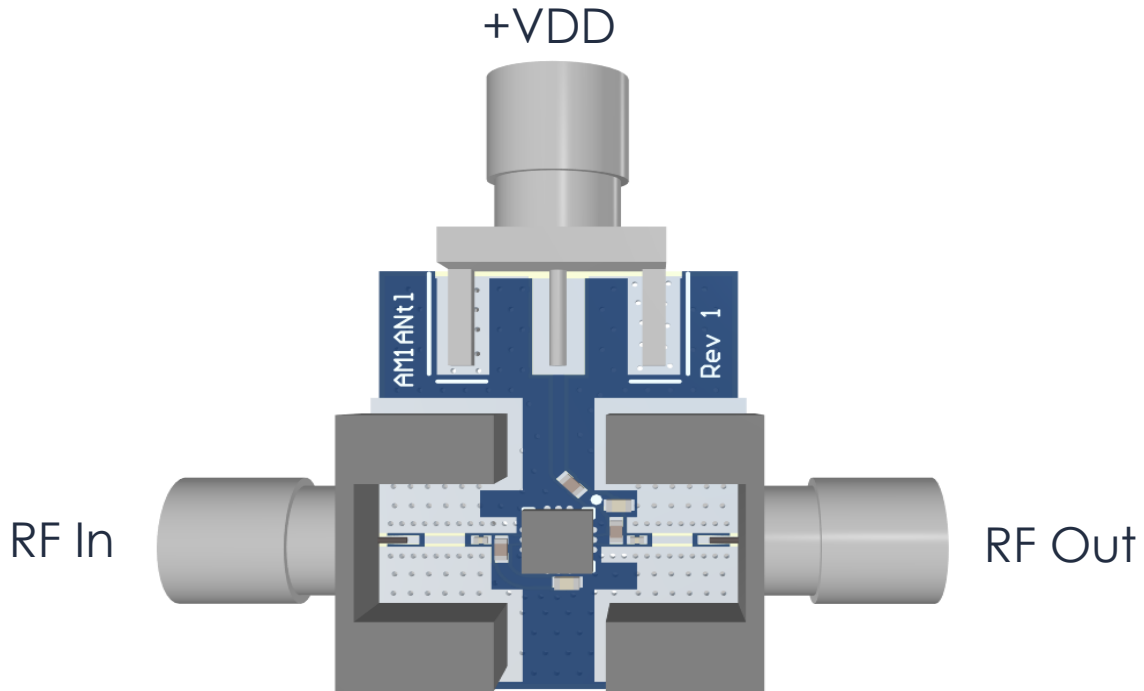
Notes:

1. Performance may be improved by replacing FB1 and FB2 with a lower loss inductor or bias tee.

AM1102 – Amplifier

DC to 22 GHz Gain Block

Evaluation PC Board



Note: Not all components shown may be installed.

Related Parts

Part Number	Description
AM1053	5 GHz to 20 GHz Gain Block
AM1070	DC to 18 GHz Broadband Gain Block
AM1071	DC to 18 GHz Broadband Gain Block
AM1100	2 GHz to 26.5 GHz Low Noise Amplifier
AM1101	2 GHz to 26.5 GHz Bypassable Amplifier
AM1163-1	DC to 10 GHz Low Noise Amplifier
AM1164-1	DC to 8 GHz Low Noise Amplifier

Component Compliance Information

RoHS: Atlanta Micro, Inc. hereby certifies that all products comply with the EC Directive 2011/65/EC on the Restriction of Hazardous Substances, commonly known as EU-RoHS 6 and 10. All products supplied by Atlanta Micro shall be compliant with the European Directive 2011/65/EC based on the following substance list.

Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylhexyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

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Atlanta Micro takes its responsibility as a global partner seriously and will use due diligence within our supply chain to ensure all standards are met to the best of our knowledge.